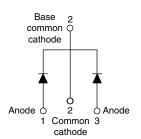


Vishay Semiconductors

Schottky Rectifier, 2 x 20 A



 E_{AS}

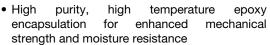


7.50 mJ

PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 20 A				
V_{R}	100 V				
V _F at I _F	0.67 V				
I _{RM} max.	11 mA at 125 °C				
T_J	175 °C				
Diode variation	Common cathode				

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop





RoHS

HALOGEN

FREE

- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability

- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	А			
V_{RRM}		100	V			
I _{FSM}	t _p = 5 μs sine	850	А			
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.67	V			
T_J	Range	- 55 to 175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-43CTQ100PbF	VS-43CTQ100-N3	UNITS	
Maximum DC reverse voltage	imum DC reverse voltage V _R 100 100		V		
Maximum working peak reverse voltage	V_{RWM}	100	100	V	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average per leg		50 % duty cycle at T _C = 135 °C, rectangular waveform		50 % duty evolo at T ₂ = 135 °C, rectangular waveform		20	
See fig. 5 per device	I _{F(AV)}			40			
Maximum peak one cycle	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and	850	A		
non-repetitive surge current per leg See fig. 7		10 ms sine or 6 ms rect. pulse	with rated V _{RRM} applied	275			
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ		
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum V_A = 1.5 x V_R typical		0.50	Α		



VS-43CTQ100PbF, VS-43CTQ100-N3

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	T _{.1} = 25 °C	0.81	V	
Maximum forward voltage drop per leg) (1)	40 A	1j=25 C	0.98		
See fig. 1	V _{FM} ⁽¹⁾	20 A	T 105 °C	0.67		
		40 A	T _J = 125 °C	0.81		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V Detectiv	1	mA	
See fig. 2		T _J = 125 °C	V _R = Rated V _R	11		
Threshold voltage	V _{F(TO)}	T T mayimum		0.71	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		0.43	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	1480	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS				UNITS	
Maximum junction and stora temperature range	ge	T _J , T _{Stg}		- 55 to 175	°C	
Maximum thermal resistance junction to case per leg	9,	Б	DC eneration	2.0		
Maximum thermal resistance junction to case per package	,	R _{thJC}	DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
				0.07	oz.	
Mounting torque -	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	$(lbf \cdot in)$	
Marking device			Case style TO-220AB	43CT	Q100	

Vishay Semiconductors

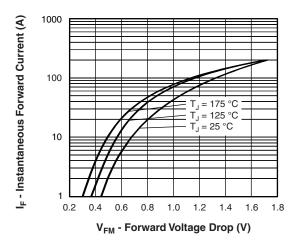


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

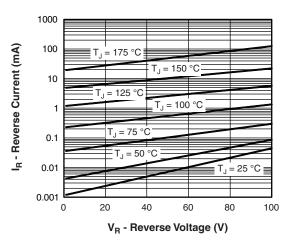


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

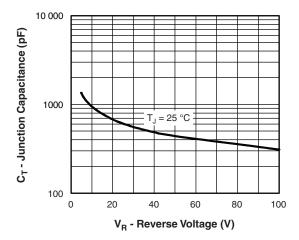


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

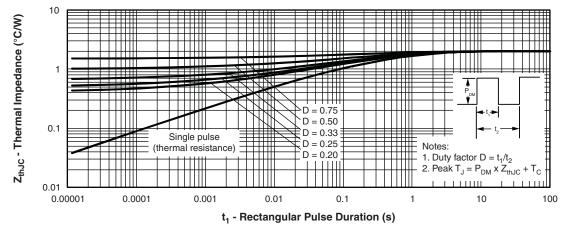


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



www.vishay.com

Vishay Semiconductors

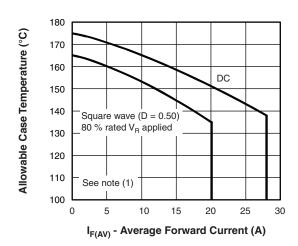


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

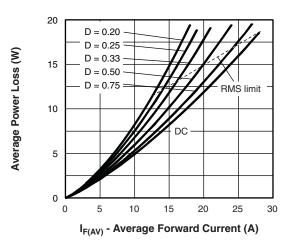


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

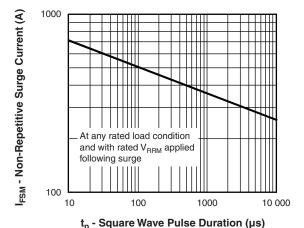


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

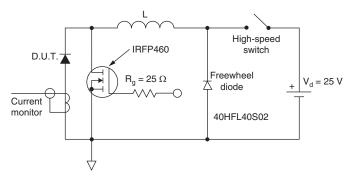


Fig. 8 - Unclamped Inductive Test Circuit

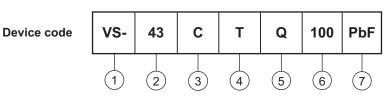
Note

 $^{(1)}$ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at (I_{F(AV)}/D) (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 10 \text{ V}$

VS-43CTQ100PbF, VS-43CTQ100-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Current rating (40 A)

3 - Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

- Voltage rating (100 = 100 V)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-43CTQ100PbF	50	1000	Antistatic plastic tube			
VS-43CTQ100-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95222			
Death are adding a information	TO-220ABPbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB-N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95065			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.